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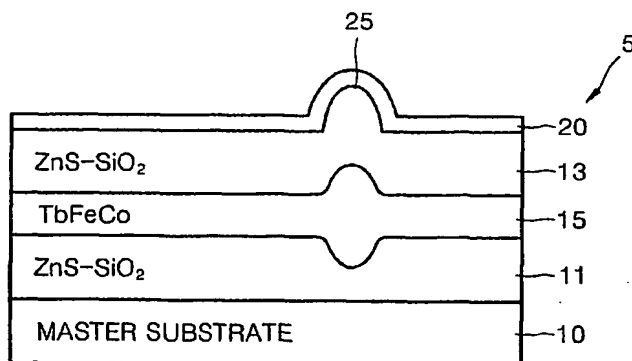
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(54) Title: RECORDED MASTER FOR MANUFACTURING INFORMATION STORAGE MEDIUM AND METHOD OF MANUFACTURING THE MASTER



(57) Abstract: A recorded master for manufacturing an information storage medium and a method of manufacturing the master are provided. The recorded master includes: a mater substrate; a heat absorption layer which is coated on the mater substrate and absorbs heat at a part on which a beam is irradiated; and a separation layer which is coated on the heat absorption layer, wherein according to the temperature distribution of the part on which the beam is irradiated, a volume change occurs in at least one of the heat absorption layer and the separation layer. With this structure, a stamper can be easily separated from a transform layer, a recorded master with a low surface roughness can be provided, and a high density information storage medium can be manufactured.

WO 2005/024813 A1